



SS52BF THRU SS520BF

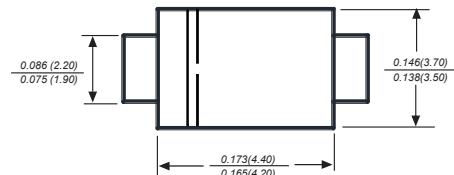
Reverse Voltage - 20 to 200 Volts Forward Current - 5.0 Ampere

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- ◆ Metal silicon junction, majority carrier conduction For surface mounted applications
- ◆ Low power loss,high efficiency
- ◆ High forward surge current capability
- ◆ For use in low voltage,high frequency inverters, free wheeling, and polarity protection applications

SMBF



Mechanical Data

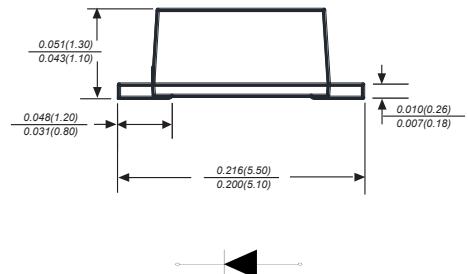
Case*: JEDEC UT BØ molded plastic body

Terminals*: Solderable per MIL-STD-750, Method 2026A

Polarity*: Polarity symbol marking on body

Mounting Position*: Any

Weight : 0.002 ounce, 0.057 grams



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

Parameter	SYMBOLS	SS52BF	SS53BF	SS54BF	SS55BF	SS56BF	SS58BF	SS510BF	SS515BF	SS520BF	UNITS
Marking Code		MDD SS52BF	MDD SS53BF	MDD SS54BF	MDD SS55BF	MDD SS56BF	MDD SS58BF	MDD SS510BF	MDD SS515BF	MDD SS520BF	
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	V
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	V
Maximum average forward rectified current at TL(see fig.1)	I _(AV)										A
Peak forward surge current 8.3ms single half sine-wave superimposed onrated load (JEDEC Method)	I _{FSM}										A
Maximum instantaneous forward voltage at 5.0A	V _F										V
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=125°C	I _R										mA
Typical junction capacitance (NOTE 1)	C _J										pF
Typical thermal resistance (NOTE 2)	R _{θJA}										°C/W
Operating junction temperature range	T _J										°C
Storage temperature range	T _{STG}										°C

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas



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Typical Characteristics

Fig.1 Forward Current Derating Curve

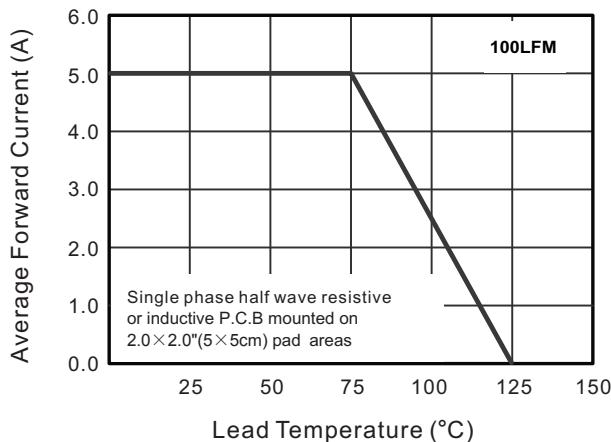


Fig.3 Typical Forward Characteristic

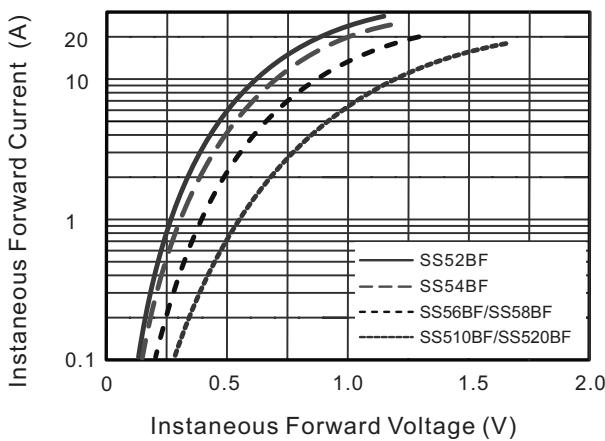
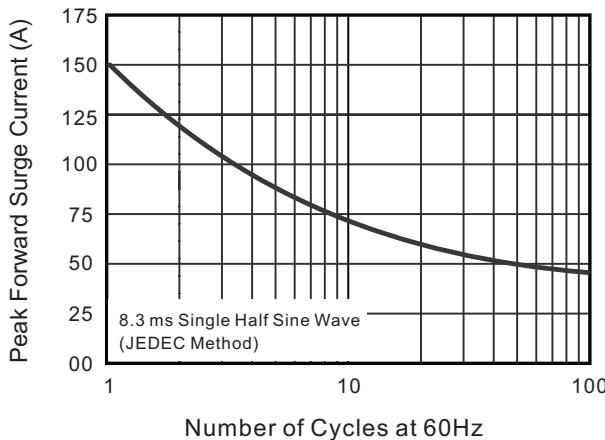


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



The curve above is for reference only.

Fig.2 Typical Reverse Characteristics

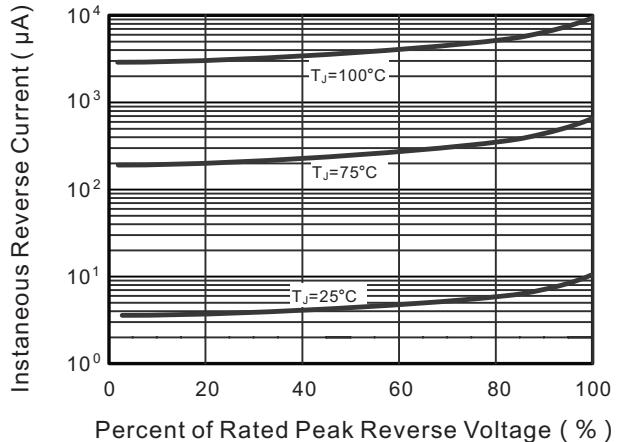


Fig.4 Typical Junction Capacitance

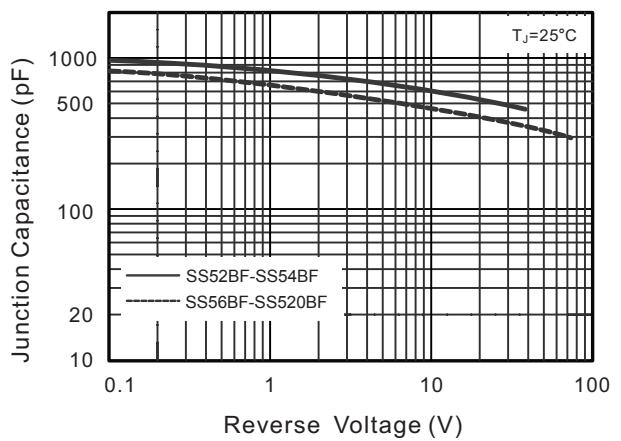
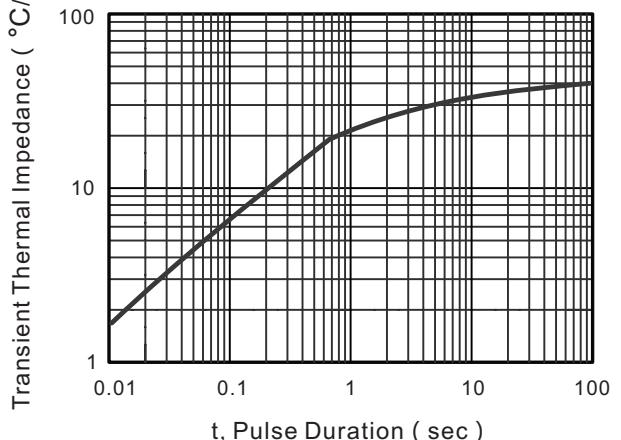
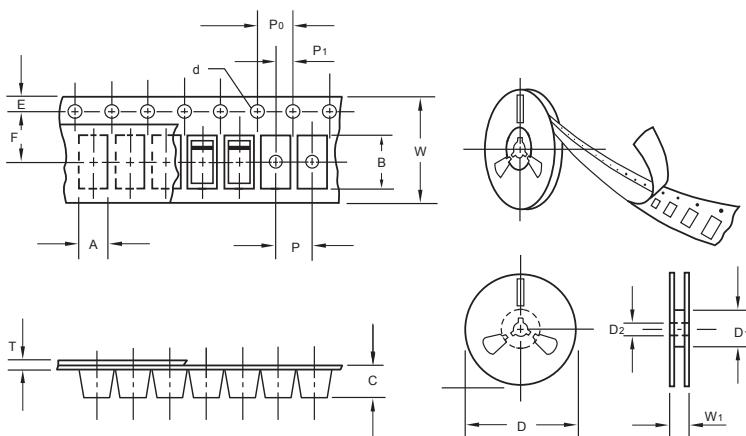


Fig.6- Typical Transient Thermal Impedance



Packing information



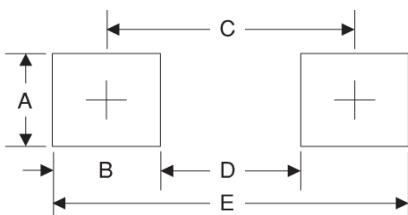
Item	Symbol	Tolerance	SMBF
Carrier width	A	0.1	3.81
Carrier length	B	0.1	5.61
Carrier depth	C	0.1	1.60
Sprocket hole	d	0.05	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D ₁	min	50.00
Feed hole diameter	D ₂	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	5.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P ₀	0.1	4.00
Embossment center	P ₁	0.1	2.00
Overall tape thickness	T	0.1	0.30
Tape width	W	0.3	12.00
Reel width	W ₁	1.0	12.30

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (mm)	BOX (pcs)	INNER BOX (mm)	REEL DIA, (mm)	CARTON SIZE (mm)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMBF	13"	5,000	4.0	10,000	190*190*41	330	365*365*360	80,000	14.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
A	2.54	0.100
B	1.8	0.071
C	4.8	0.189
D	3.0	0.118
E	6.6	0.260

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